TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SC5458

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications DC-AC Inverter Applications

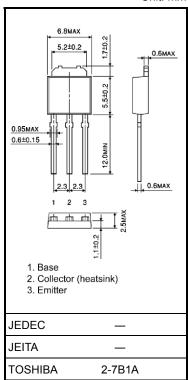
• Excellent switching times: t<sub>r</sub> = 0.5 µs (max)

$$t_f = 0.3 \ \mu s \ (max) \ (I_C = 0.4 \ A)$$

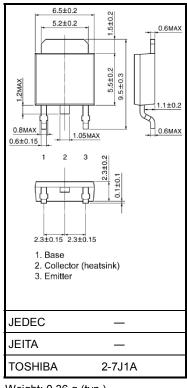
• High collector breakdown voltage:  $V_{CEO} = 400 \text{ V}$ 

### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	600	V	
Collector-emitter voltage		V <sub>CEO</sub>	400	V	
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	Ι <sub>C</sub>	0.8	A	
	Pulse	I <sub>CP</sub>	1.5		
Base current		Ι <sub>Β</sub>	0.5	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	w	
	Tc = 25°C	гC	10		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



#### Weight: 0.36 g (typ.)



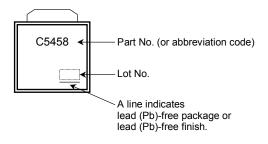
Weight: 0.36 g (typ.)

Unit: mm

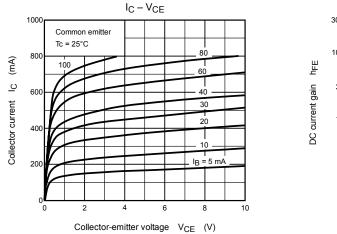
## Electrical Characteristics (Ta = 25°C)

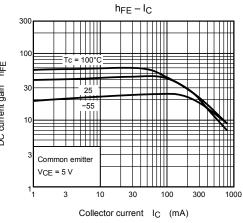
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	current	I <sub>CBO</sub>	V <sub>CB</sub> = 480 V, I <sub>E</sub> = 0	_	—	100	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	100	μA
Collector-base breakdown voltage		V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	600	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	400	_	_	V
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	20	—	—	
			V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 A	30	_	80	
Collector emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.04 A	_	_	1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.04 A	_	_	1.3	V
-	Turn-on time	tr	$20 \ \mu s \qquad  B1 \qquad OUTPUT \\ \downarrow \qquad \downarrow \qquad INPUT \circ \qquad \downarrow \qquad$	_	—	0.5	με
	Storage time	t <sub>stg</sub>		_	_	2.0	
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = 50 mA, I <sub>B2</sub> = −100 mA DUTY CYCLE ≤ 1%	_	_	0.3	

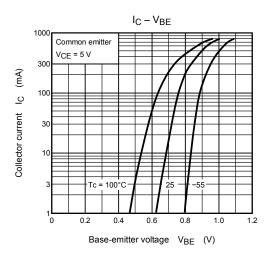
## Marking

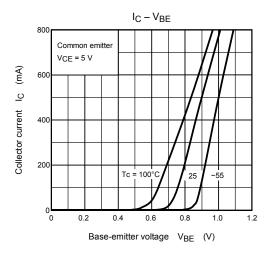


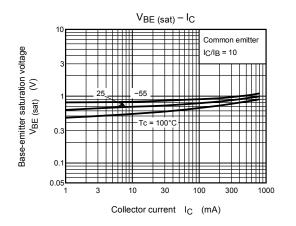
## **TOSHIBA**

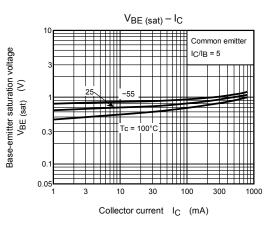


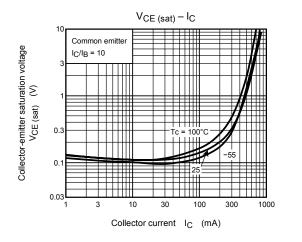


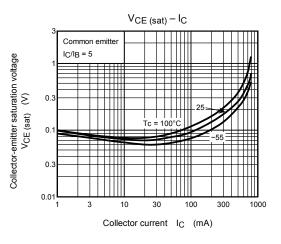


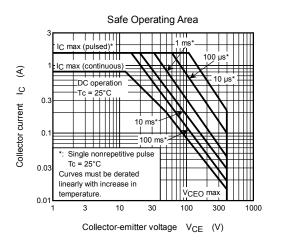












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